April 2012

FDS3672

FAIRCHILD

FDS3672

N-Channel PowerTrench[®] MOSFET 100V, 7.5A, 22m Ω

Features

- $r_{DS(ON)} = 19m\Omega$ (Typ.), $V_{GS} = 10V$, $I_D = 7.5A$
- $Q_g(tot) = 28nC (Typ.), V_{GS} = 10V$
- Low Miller Charge
- Low Q_{RR} Body Diode
- Optimized efficiency at high frequencies
- UIS Capability (Single Pulse and Repetitive Pulse)

Applications

- DC/DC converters and Off-Line UPS
- Distributed Power Architectures and VRMs
- Primary Switch for 24V and 48V Systems
- High Voltage Synchronous Rectifier

Formerly developmental type 82763

Branding Dash





MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units V	
V _{DSS}	Drain to Source Voltage	100		
V _{GS}	Gate to Source Voltage	±20	V	
I _D	Drain Current			
	Continuous (T _A = 25 ^o C, V _{GS} = 10V, $R_{\theta JA}$ = 50 ^o C/W)	7.5	A	
	Continuous (T _A = 100°C, V _{GS} = 10V, R _{θJA} = 50°C/W)	4.8	A	
	Pulsed	Figure 4	A	
E _{AS}	Single Pulse Avalanche Energy (Note 1)	416	mJ	
D	Power dissipation	2.5	W	
P _D	Derate above 25°C	20	mW/ºC	
T _J , T _{STG}	Operating and Storage Temperature	-55 to 150	°C	

Thermal Characteristics

$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient at 10 seconds (Note 3)	50	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient at 1000 seconds (Note 3)	85	°C/W
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case (Note 2)	25	°C/W

Package Marking and Ordering Information

EDS3672 EDS3672 SO-8 330mm 12mm 2500 un	Device Marking	Device	Package	Reel Size	Tape Width	Quantity
	FDS3672	FDS3672	SO-8	330mm	12mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	octeristics					
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	100	-	-	V
1	Zoro Coto Voltogo Droip Current	V _{DS} = 80V	-	-	1	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V \qquad T_C = 150^{\circ}C$	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA
On Chara	cteristics					
V _{GS(TH)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	-	4	V
00(11)		I _D = 7.5A, V _{GS} = 10V	-	0.019	0.023	
-	Drain to Source On Desistance	$I_{\rm D} = 6.8$ A, $V_{\rm GS} = 6$ V	-	0.023	0.028	
^r ds(on)	Drain to Source On Resistance	$I_D = 7.5A, V_{GS} = 10V,$ $T_C = 150^{\circ}C$	-	0.035	0.043	Ω
Dynamic	Characteristics					
C _{ISS}	Input Capacitance		-	2015	-	pF
C _{OSS}	Output Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	-	285	-	pF
C _{RSS}	Reverse Transfer Capacitance		-	70	-	pF
Q _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0V$ to 10V	-	28	37	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{GS} = 0V \text{ to } 2V$ $V_{DD} = 50V$	-	4	6	nC
Q _{gs}	Gate to Source Gate Charge	I _D = 7.5A	-	10	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau	I _g = 1.0mA	-	6.8	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		-	6	-	nC
Switching	g Characteristics (V _{GS} = 10V)					
t _{ON}	Turn-On Time		-	-	51	ns
t _{d(ON)}	Turn-On Delay Time		-	14	-	ns
t _r	Rise Time	$V_{DD} = 50V, I_{D} = 4A$	-	20	-	ns
t _{d(OFF)}	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 10\Omega$	-	37	-	ns
t _f	Fall Time		-	27	-	ns
t _{OFF}	Turn-Off Time		-	-	96	ns
Drain-Sou	urce Diode Characteristics					
Var	Source to Drain Diode Voltage	I _{SD} = 7.5A	-	-	1.25	V
V _{SD}	Source to Drain Diode Voltage	$I_{SD} = 4A$	-	-	1.0	V
t _{rr}	Reverse Recovery Time	I_{SD} = 7.5A, d I_{SD} /dt= 100A/µs	-	-	55	ns
Q _{RR}	Reverse Recovered Charge	I _{SD} = 7.5A, dI _{SD} /dt= 100A/μs	-	-	90	nC

Notes:
1: Starting T_J = 25°C, L = 13mH, I_{AS} = 8A.
2: R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{θJC} is guaranteed by design while R_{θCA} is determined by the user's board design.
3: R_{θJA} is measured with 1.0 in² copper on FR-4 board

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